

MBR1035 ~ MBR1060

PRV : 35~60 Volts
Io : 10 Amperes

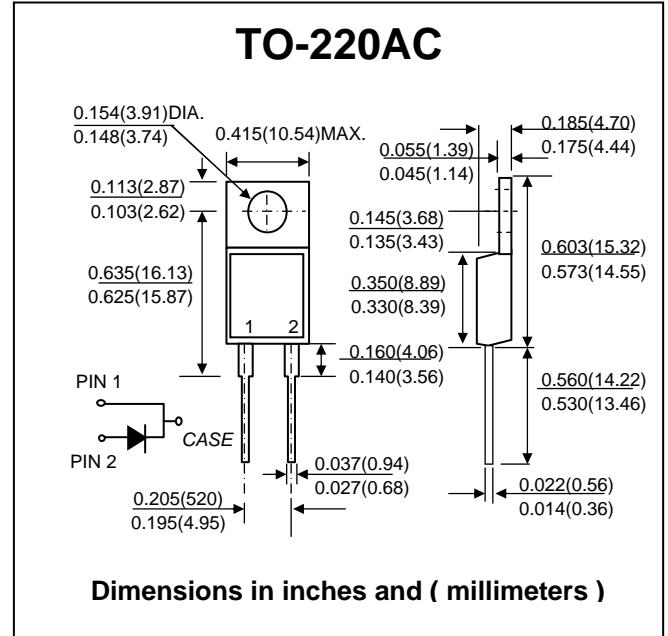
FEATURES :

- * Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- * Metal silicon junction, majority carrier conduction
- * Low power loss, high efficiency
- * Guardring for overvoltage protection
- * For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- * High temperature soldering : 250°C/10 seconds, 0.25" (6.35mm) from case
- * **Pb / RoHS Free**

MECHANICAL DATA :

- * Case : JEDEC TO-220AC molded plastic body
- * Terminals: Plated leads, solderable per MIL-STD-750 Method 2026
- * Polarity: As marked
- * Mounting Position: Any
- * Weight : 2.24 grams (Approximately)

SCHOTTKY BARRIER RECTIFIER DIODES



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_c = 25 °C unless otherwise noted)

RATINGS	SYMBOL	MBR1035	MBR1045	MBR1050	MBR1060	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	V
Maximum Working Peak Reverse Voltage	V _{RWM}	35	45	50	60	V
Maximum DC Blocking Voltage	V _{DC}	35	45	50	60	V
Maximum Average Forward Rectified Current (See Fig. 1)	I _{F(AV)}	10				A
Peak Forward Surg Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150				A
Maximum Instantaneous Forward Voltage (Note 1)	V _F	-		0.80		V
at I _F = 10 A, T _C = 125 °C				0.70		
Maximum Average Reverse Current at T _C = 25 °C	I _R	0.10				mA
Rate Peak Reverse Voltage T _C = 125 °C		15				
Typical Thermal Resistance	R _{θJC}	2.0				°C/W
Operating Junction Temperature Range	T _J	-65 to + 150				°C
Storage Temperature Range	T _{STG}	-65 to + 175				°C

Note :

(1) Pulse test : 300 μs pluse width, 1% duty cycle

RATING AND CHARACTERISTIC CURVES (MBR1035 ~ MBR1060)

FIG.1 - FORWARD CURRENT DERATING CURVE

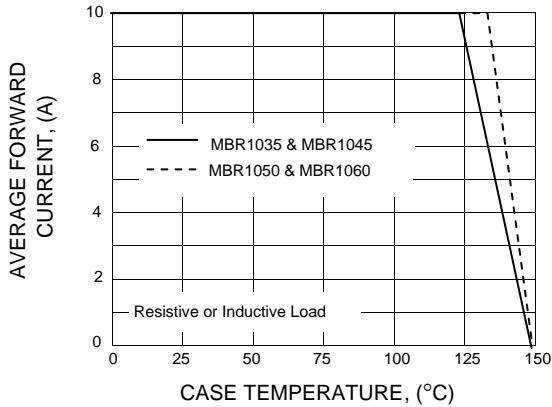


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

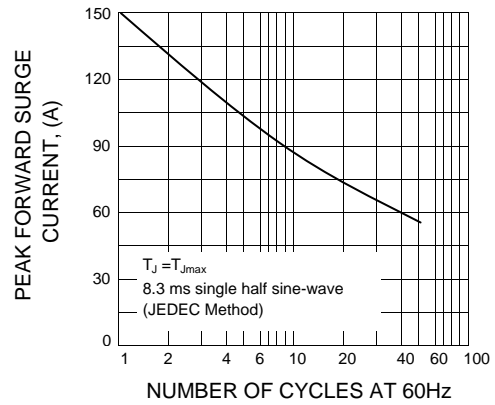


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

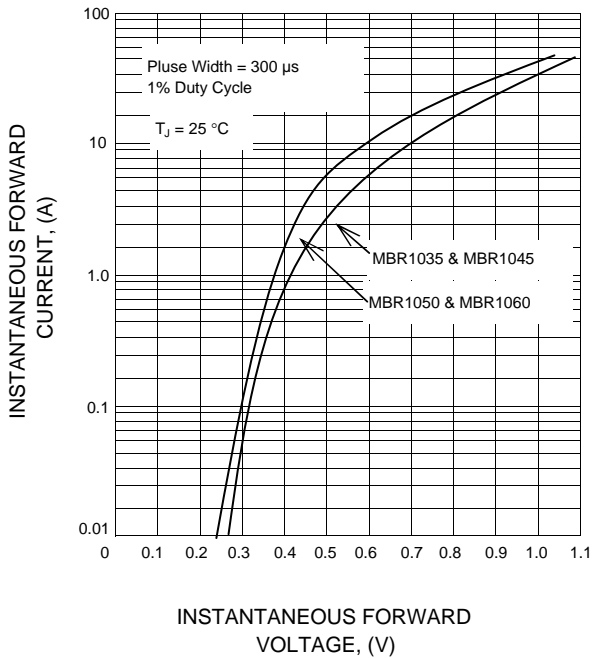


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

